



PNP SILICON PLANAR MEDIUM POWER TRANSISTORS IN SOT223

Features

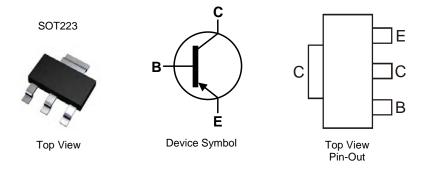
- I_C = -1A Continuous Collector Current
- Low Saturation Voltage V_{CE(sat)} < -500mV @ -0.5A
- Gain groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary NPN types: BCP54, 55 and 56
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Devices (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (Approximate)

Applications

- Medium Power Switching or Amplification Applications
- AF driver and output stages



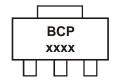
Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCP51TA	BCP 51	7	12	1,000
BCP5110TA	BCP 5110	7	12	1,000
BCP5116TA	BCP 5116	7	12	1,000
BCP5116TC	BCP 5116	13	12	4,000
BCP52TA	BCP 52	7	12	1,000
BCP5210TA	BCP 5210	7	12	1,000
BCP5216TA	BCP 5216	7	12	1,000
BCP53TA	BCP 53	7	12	1,000
BCP5310TA	BCP 5310	7	12	1,000
BCP5316TA	BCP 5316	7	12	1,000
BCP5316TC	BCP 5316	13	12	4,000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website $\mbox{\sc http://www.diodes.com}$

Marking Information



BCP = Product Type Marking Code, Line 1. xxxx = Product Type Marking Code, Line 2 as follows:

 BCP51
 = 51
 BCP52
 = 52
 BCP53
 = 53

 BCP5110
 = 5110
 BCP5210
 = 5210
 BCP5310
 = 5310

 BCP5116
 = 5116
 BCP5216
 = 5216
 BCP5316
 = 5316

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Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	BCP51	BCP52	BCP53	Unit	
Collector-Base Voltage	V _{CBO}	-45	-60	-100	V	
Collector-Emitter Voltage	V _{CEO}	-45	-60	-80	V	
Emitter-Base Voltage	V_{EBO}		-5			
Continuous Collector Current	Ic		-1			
Peak Pulse Collector Current	I _{CM}	-2			A	
Continuous Base Current	I _B	-100			A	
Peak Pulse Base Current	I _{BM}	-200			mA mA	

Thermal Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _D	2	W
Thermal Resistance, Junction to Ambient (Note 4)	$R_{\theta JA}$	62	°C/W
Thermal Resistance, Junction to Leads (Note 5)	R _{θJL}	19.4	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

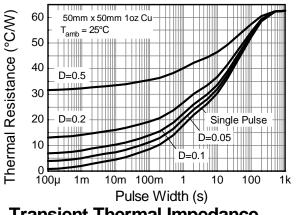
Notes:

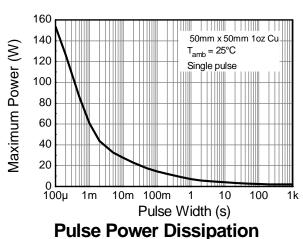
^{4.} For a device surface mounted on 50mm X 50mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

5. Thermal resistance from junction to solder-point (at the end of the collector lead).



Thermal Characteristics





Transient Thermal Impedance

Max Power Dissipation (W) 2.0 50mm x 50mm 1oz Cu 1.5 1.0 0.5 60 80 100 120 140 Temperature (°C)

Derating Curve

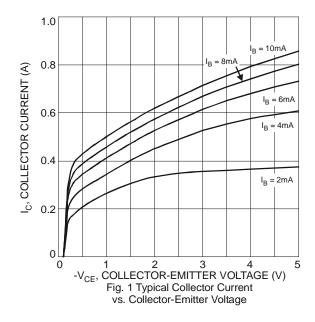
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Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector Doos	BCP51		-45				
Collector-Base Breakdown Voltage	BCP52	BV _{CBO}	-60	-	-	V	$I_{C} = -100 \mu A$
Breakdown Voltage	BCP53		-100				
Collector-Emitter	BCP51		-45			V	I _C = -10mA
Breakdown Voltage (Note 6)	BCP52	BV _{CEO}	-60	-	-		
Breakdown Voltage (Note 0)	BCP53	1	-80				
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	-	-	V	$I_E = -10\mu A$
Collector Cut-off Current					-0.1	^	$V_{CB} = -30V$
Collector Cut-on Current		ICBO	-	-	-20	μA	$V_{CB} = -30V, T_A = 150^{\circ}C$
Emitter Cut-off Current		I _{EBO}	i	-	-20	nA	$V_{EB} = -4V$
		s h _{FE}	25	-	-		$I_C = -5mA$, $V_{CE} = -2V$
	All versions		40	-	250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Ratio (Note 6)			25	-	-		$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
	10 gain grp		63	-	160		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
	16 gain grp		100	-	250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
Collector-Emitter Saturation Voltage (Note 6)		V _{CE(sat)}	-	-	-0.5	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 6)		V _{BE(on)}	-	-	-1.0	V	$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
Transition Frequency		f⊤	150	-	-	MHz	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz
Output Capacitance		Cobo	-	-	25	pF	$V_{CB} = -10V$, $f = 1MHz$

Notes: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



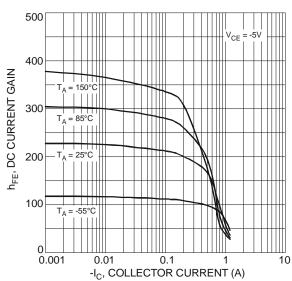


Fig. 2 Typical DC Current Gain vs. Collector Current



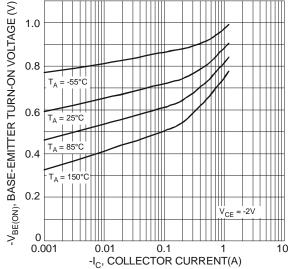


Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

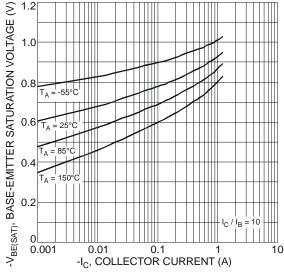


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

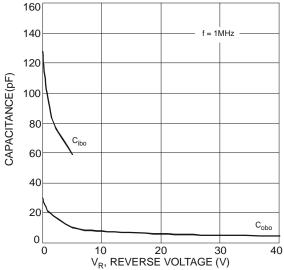


Fig. 7 Typical Capacitance Characteristics

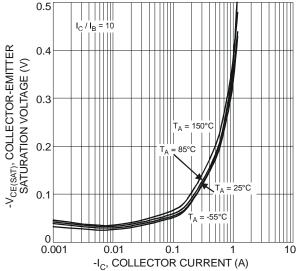


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

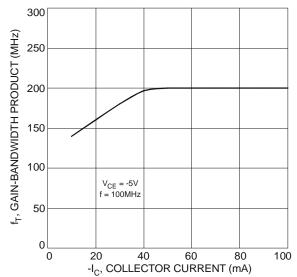
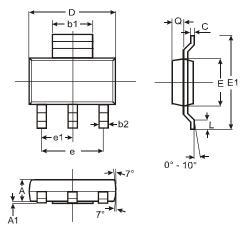


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current

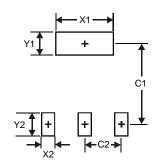


Package Outline Dimensions



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)			
X1	3.3			
X2	1.2			
Y1	1.6			
Y2	1.6			
C1	6.4			
C2	2.3			



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